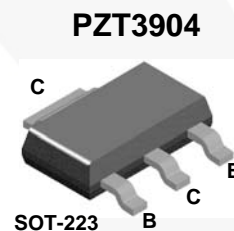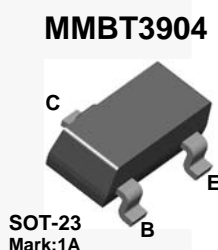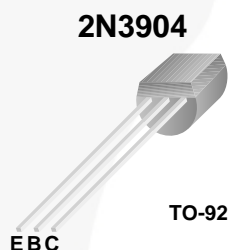**FAIRCHILD**™

October 2014

2N3904 / MMBT3904 / PZT3904
NPN General-Purpose Amplifier

Description

This device is designed as a general-purpose amplifier and switch. The useful dynamic range extends to 100 mA as a switch and to 100 MHz as an amplifier.

2N3904

TO-92

E B C

MMBT3904

C

E

B

SOT-23
Mark:1A

PZT3904

C

E

C

B

SOT-223

Ordering Information

Part Number	Marking	Package	Packing Method	Pack Quantity
2N3904BU	2N3904	TO-92 3L	Bulk	10000
2N3904TA	2N3904	TO-92 3L	Ammo	2000
2N3904TAR	2N3904	TO-92 3L	Ammo	2000
2N3904TF	2N3904	TO-92 3L	Tape and Reel	2000
2N3904TFR	2N3904	TO-92 3L	Tape and Reel	2000
MMBT3904	1A	SOT-23 3L	Tape and Reel	3000
PZT3904	3904	SOT-223 4L	Tape and Reel	2500

Absolute Maximum Ratings[1], [2]

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only. Values are at T_A = 25°C unless otherwise noted.

Symbol	Parameter	Value	Unit
V_{CEO}	Collector-Emitter Voltage	40	V
V_{CBO}	Collector-Base Voltage	60	V
V_{EBO}	Emitter-Base Voltage	6.0	V
I_C	Collector Current - Continuous	200	mA
T_J, T_{STG}	Operating and Storage Junction Temperature Range	-55 to 150	°C

Notes:

1. These ratings are based on a maximum junction temperature of 150°C.

2. These are steady-state limits. Fairchild Semiconductor should be consulted on applications involving pulsed or low-duty cycle operations.

Thermal Characteristics

Values are at T_A = 25°C unless otherwise noted.

Symbol	Parameter	Maximum			Unit
		2N3904	MMBT3904[3]	PZT3904[4]	
P_D	Total Device Dissipation	625	350	1,000	mW
	Derate Above 25°C	5.0	2.8	8.0	mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	83.3			°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	200	357	125	°C/W

Notes:

3. Device is mounted on FR-4 PCB 1.6 inch X 1.6 inch X 0.06 inch.

4. Device is mounted on FR-4 PCB 36 mm X 18 mm X 1.5 mm, mounting pad for the collector lead minimum 6 cm^2.

Electrical Characteristics

Values are at T_A = 25°C unless otherwise noted.

Symbol	Parameter	Conditions	Min.	Max.	Unit
OFF CHARACTERISTICS					
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage	I_C = 1.0 mA, I_B = 0	40		V
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage	I_C = 10 µA, I_E = 0	60		V
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage	I_E = 10 µA, I_C = 0	6.0		V
I_{BL}	Base Cut-Off Current	V_{CE} = 30 V, V_{EB} = 3 V		50	nA
I_{CEX}	Collector Cut-Off Current	V_{CE} = 30 V, V_{EB} = 3 V		50	nA
ON CHARACTERISTICS[5]					
h_{FE}	DC Current Gain	I_C = 0.1 mA, V_{CE} = 1.0 V	40		
		I_C = 1.0 mA, V_{CE} = 1.0 V	70		
		I_C = 10 mA, V_{CE} = 1.0 V	100	300	
		I_C = 50 mA, V_{CE} = 1.0 V	60		
		I_C =100 mA, V_{CE} = 1.0V	30		
V_{CE}(sat)	Collector-Emitter Saturation Voltage	I_C = 10 mA, I_B = 1.0 mA		0.2	V
		I_C = 50 mA, I_B = 5.0 mA		0.3	
V_{BE}(sat)	Base-Emitter Saturation Voltage	I_C = 10 mA, I_B = 1.0 mA	0.65	0.85	V
		I_C = 50 mA, I_B = 5.0 mA		0.95	
SMALL SIGNAL CHARACTERISTICS					
f_T	Current Gain - Bandwidth Product	I_C = 10 mA, V_{CE} = 20 V, f = 100 MHz	300		MHz
C_{obo}	Output Capacitance	V_{CB} = 5.0 V, I_E = 0, f = 100 kHz		4.0	pF
C_{ibo}	Input Capacitance	V_{EB} = 0.5 V, I_C = 0, f = 100 kHz		8.0	pF
NF	Noise Figure	I_C = 100 µA, V_{CE} = 5.0 V, R_S = 1.0 kΩ, f = 10 Hz to 15.7 kHz		5.0	dB
SWITCHING CHARACTERISTICS					
t_d	Delay Time	V_{CC} = 3.0 V, V_{BE} = 0.5 V I_C = 10 mA, I_{B1} = 1.0 mA		35	ns
t_r	Rise Time			35	ns
t_s	Storage Time	V_{CC} = 3.0 V, I_C = 10 mA, $I_{B1} = I_{B2}$ = 1.0 mA		200	ns
t_f	Fall Time			50	ns

Note:

5. Pulse test: pulse width ≤ 300 µs, duty cycle ≤ 2.0%.
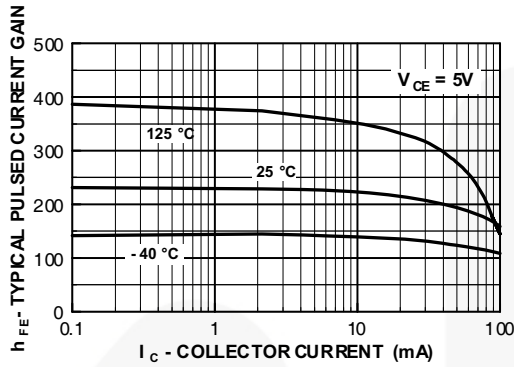
Typical Performance Characteristics

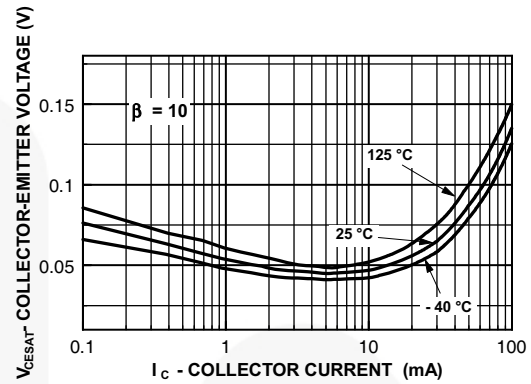Figure 1. Typical Pulsed Current Gain vs. Collector
Current

Figure 2. Collector-Emitter Saturation Voltage vs.
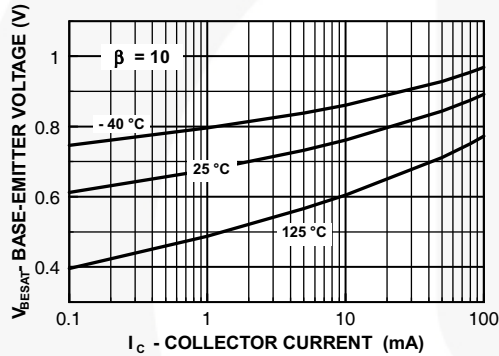Collector Current

Figure 3. Base-Emitter Saturation Voltage
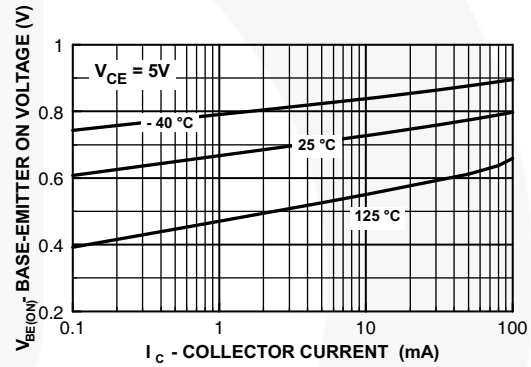vs. Collector Current

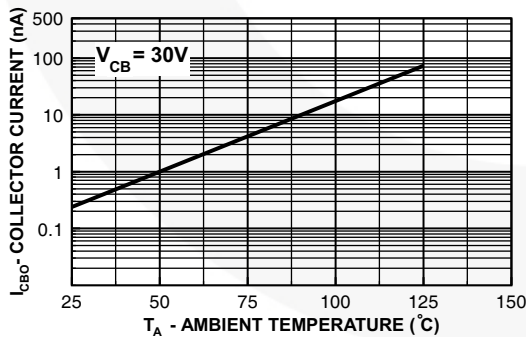Figure 4. Base-Emitter On Voltage vs.
Collector Current

Figure 5. Collector Cut-Off Current vs.
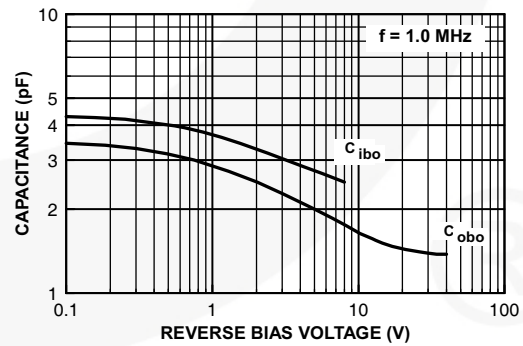Ambient Temperature

Figure 6. Capacitance vs. Reverse Bias Voltage

Typical Performance Characteristics (Continued)
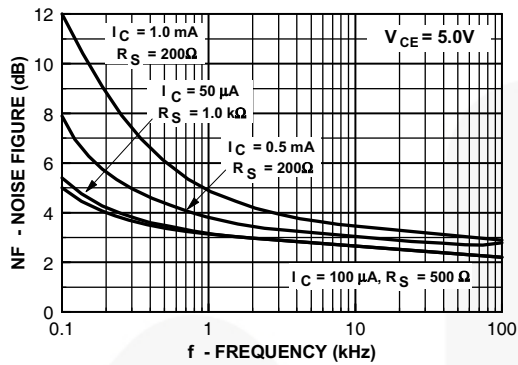

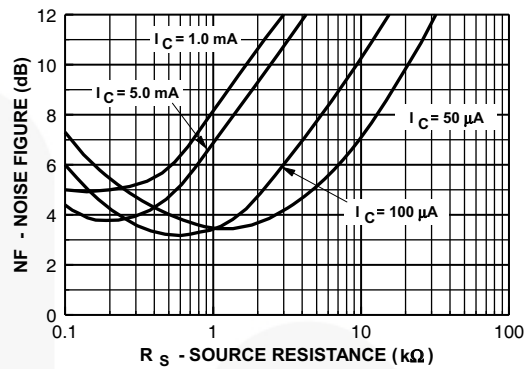Figure 7. Noise Figure vs. Frequency

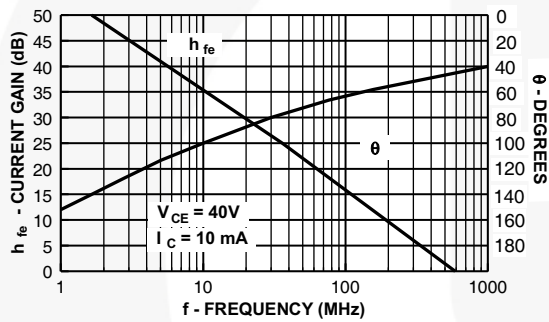Figure 8. Noise Figure vs. Source Resistance

Figure 9. Current Gain and Phase Angle vs. Frequency
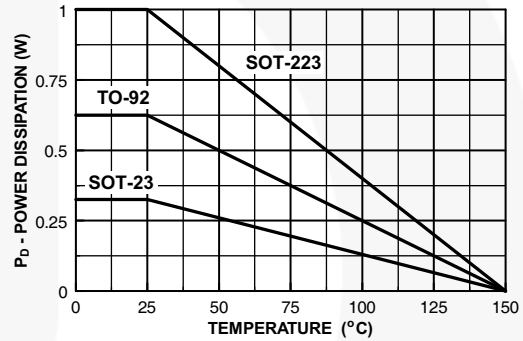

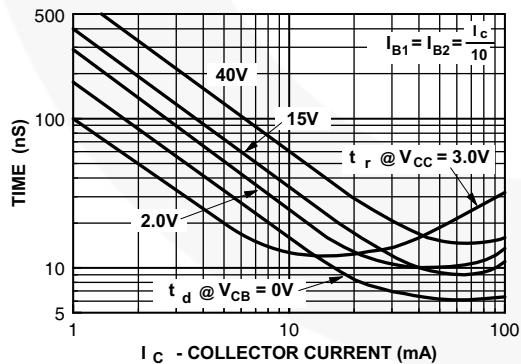Figure 10. Power Dissipation vs. Ambient Temperature
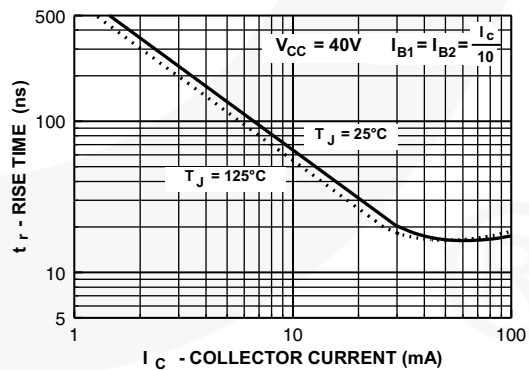

Figure 11. Turn-On Time vs. Collector Current

Figure 12. Rise Time vs. Collector Current

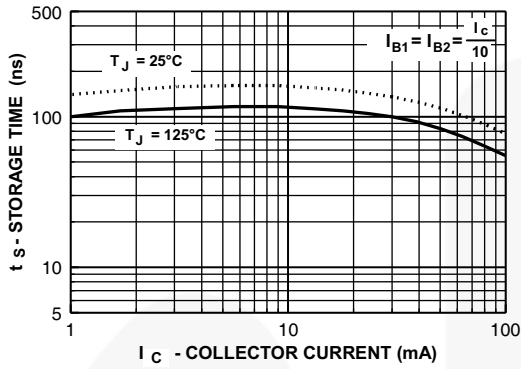## Typical Performance Characteristics (Continued)

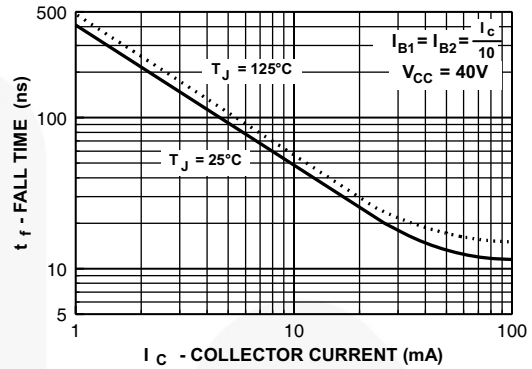Figure 13. Storage Time vs. Collector Current

Figure 14. Fall Time vs. Collector Current

Figure 15. Current Gain
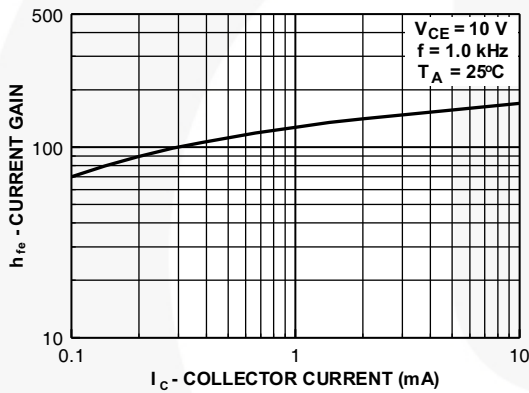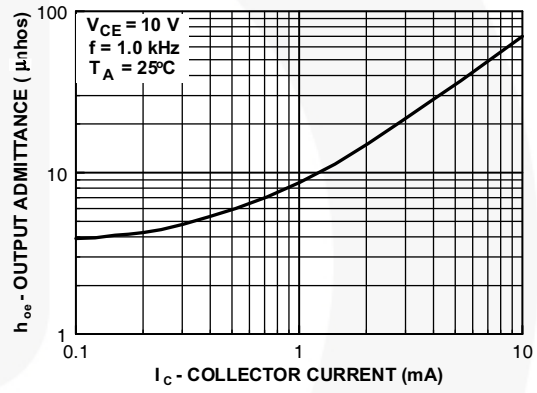
Figure 16. Output Admittance
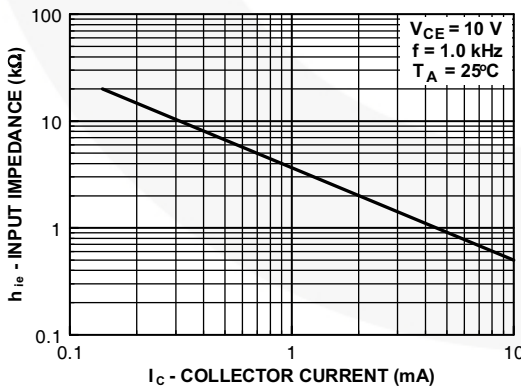
Figure 17. Input Impedance
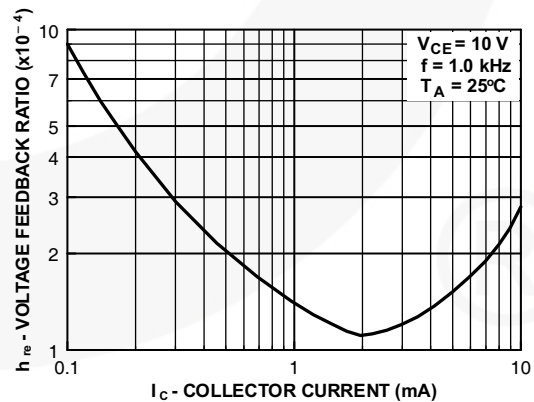
Figure 18. Voltage Feedback Ratio

Test Circuits
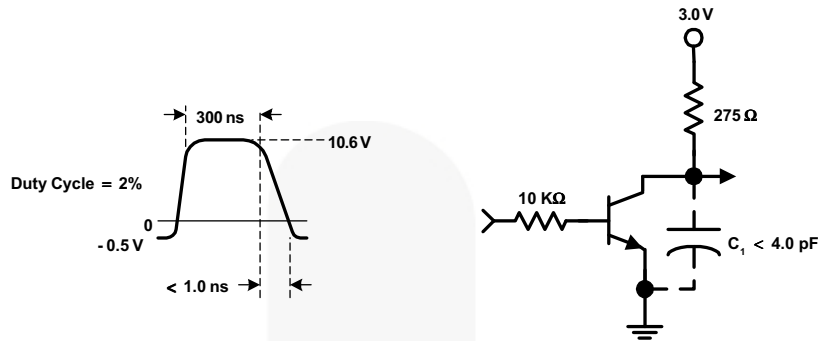
Figure 19. Delay and Rise Time Equivalent Test Circuit
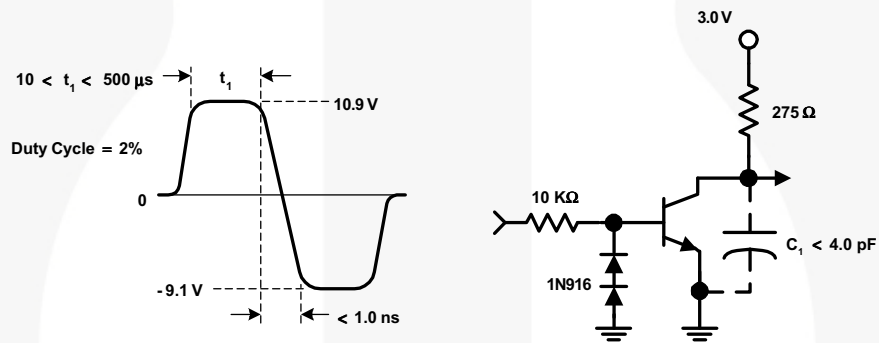
Figure 20. Storage and Fall Time Equivalent Test Circuit

5.20
4.32

5.33
4.32

3.44
2.54

13.00
10.50

1   2   3

0.56
0.36

2.80
2.40

0.52
0.30

4.19
3.05

1   2   3

2.66
2.13

NOTES: UNLESS OTHERWISE SPECIFIED
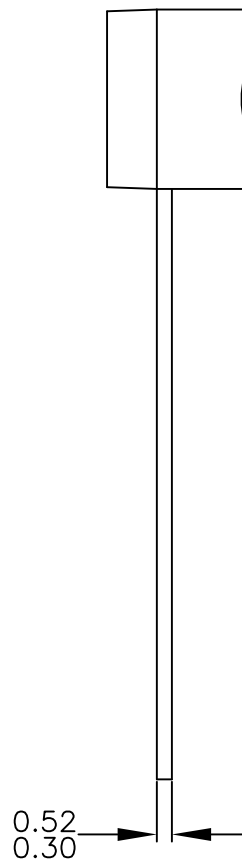
A.   DRAWING CONFORMS TO JEDEC MS-013,
      VARIATION AC.
B.   ALL DIMENSIONS ARE IN MILLIMETERS.
C.   DRAWING CONFORMS TO ASME Y14.5M-2009.
D.   DRAWING FILENAME: MKT-ZA03FREV3.
E.   FAIRCHILD SEMICONDUCTOR.
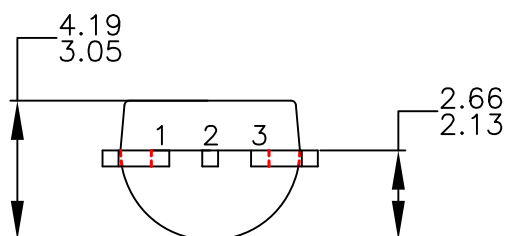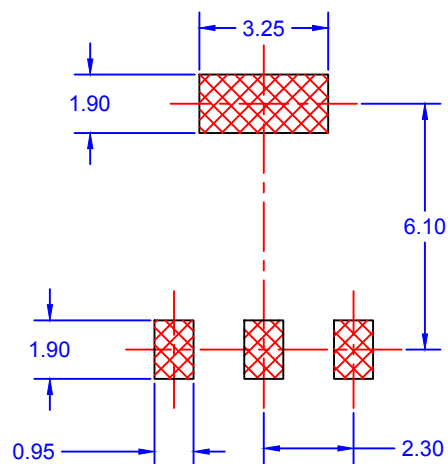
6.70
6.20

⊕ 0.10Ⓜ C B

3.10
2.90

4

A

3.70
3.30

1   3

0.84
0.60

2.30

4.60

⊕ 0.10Ⓜ C B

3.25

1.90

6.10

1.90

0.95   2.30

LAND PATTERN RECOMMENDATION

1.80 MAX

C   0.10
0.00

⌒ 0.08Ⓜ C

SEE DETAIL A

7.30
6.70
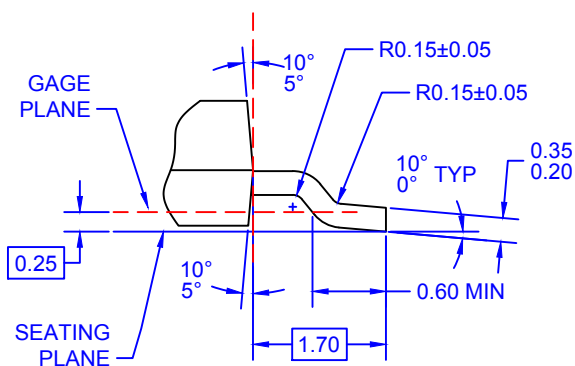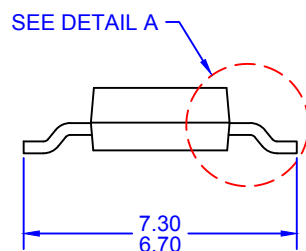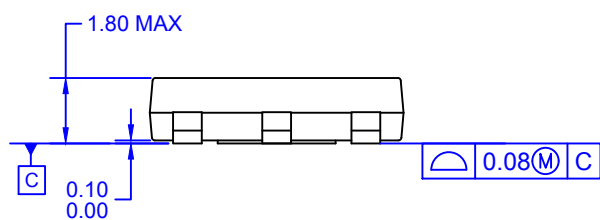
NOTES: UNLESS OTHERWISE SPECIFIED
  A) DRAWING BASED ON JEDEC REGISTRATION
      TO-261C, VARIATION AA.
  B) ALL DIMENSIONS ARE IN MILLIMETERS.
  C) DIMENSIONS DO NOT INCLUDE BURRS
      OR MOLD FLASH. MOLD FLASH OR BURRS
      DOES NOT EXCEED 0.10MM.
  D) DIMENSIONING AND TOLERANCING PER
      ASME Y14.5M-2009.
  E) LANDPATTERN NAME: SOT230P700X180-4BN
  F) DRAWING FILENAME: MKT-MA04AREV3

10°
5°   R0.15±0.05

GAGE
PLANE   R0.15±0.05

10°   0.35
0° TYP   0.20

0.25

10°
5°   0.60 MIN

SEATING
PLANE

1.70

FAIRCHILD™

DETAIL A
SCALE: 2:1

5.20
4.32

5.33
4.32

(0.81)
(0.79)

15.62
13.20

1   2   3

0.56
0.36

0.52
0.30

1.27

2.54

4.19
3.05

1   2   3

2.66
2.13
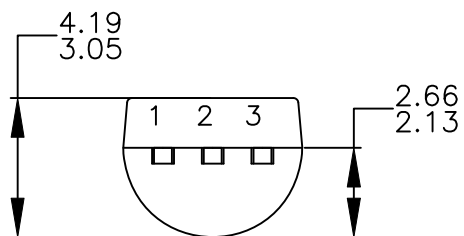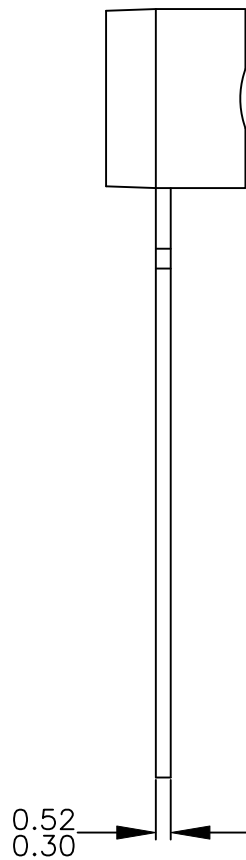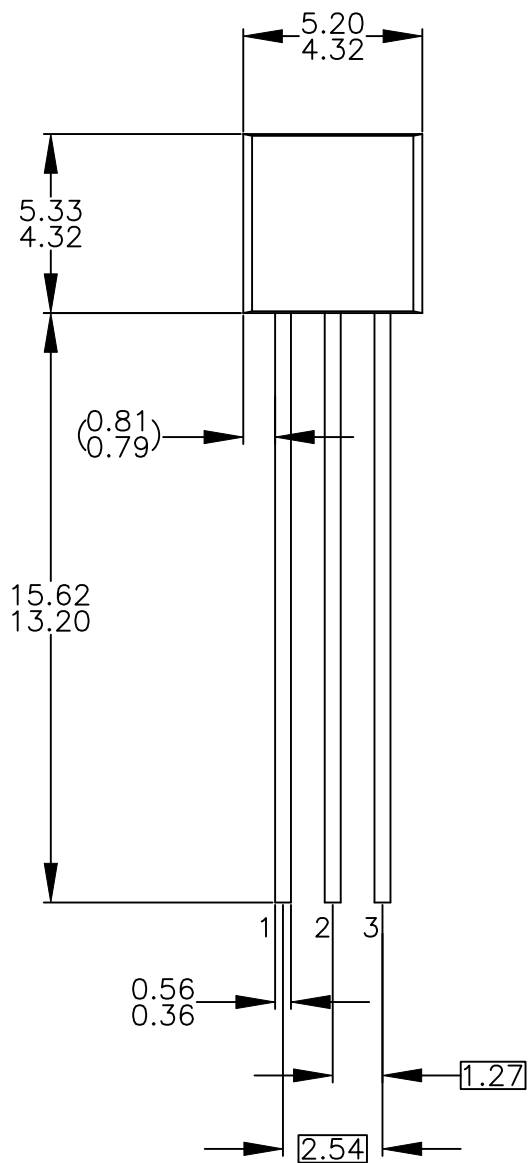
NOTES: UNLESS OTHERWISE SPECIFIED

A)   DRAWING WITH REFERENCE TO JEDEC TO-92
     RECOMMENDATIONS.
B)   ALL DIMENSIONS ARE IN MILLIMETERS.
C)   DRAWING CONFORMS TO ASME Y14.5M-2009.
D)   DRAWING FILENAME: MKT-ZA03DREV4.

FAIRCHILD™

2.92±0.20 A

3

B

1.30 +0.20 / -0.15

(0.29)

0.95

1

2

0.60 / 0.37

1.90

⊕ | 0.20 Ⓜ | A | B

0.95

1.40

2.20

1.90

1.00

LAND PATTERN
RECOMMENDATION

1.20 MAX

(0.93)

0.10 / 0.00

C

⌒ | 0.10 Ⓜ | C

SEE DETAIL A

2.40±0.30

GAGE PLANE

0.23 / 0.08

0.25

0.20 MIN

(0.55)

SEATING PLANE
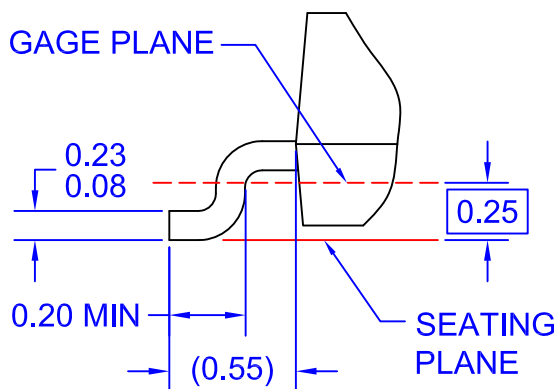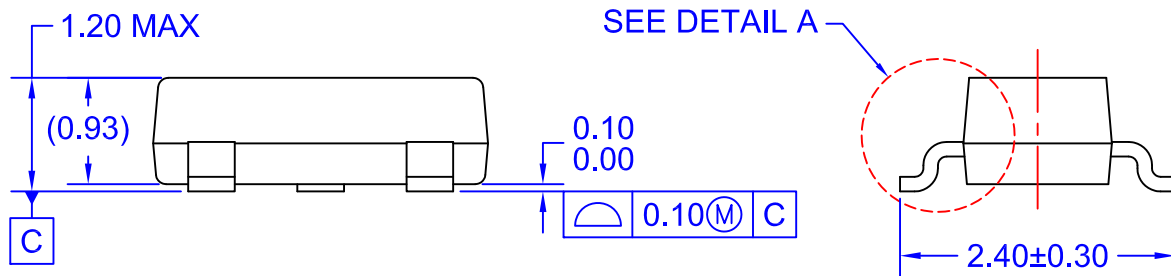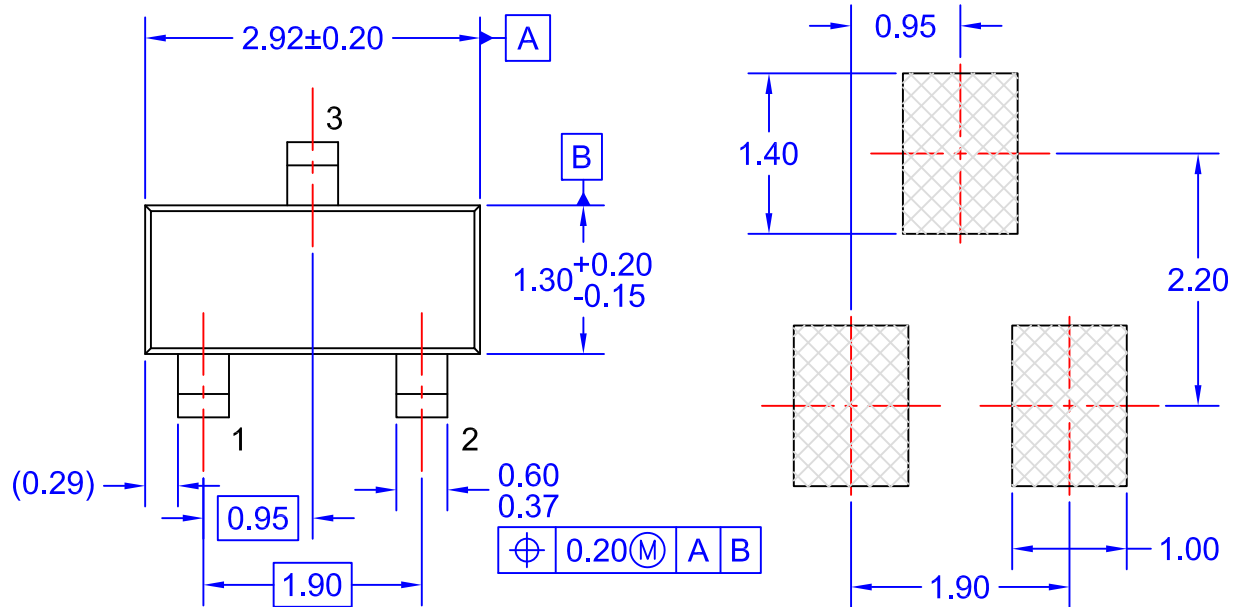
DETAIL A
SCALE: 2X

NOTES: UNLESS OTHERWISE SPECIFIED

A) REFERENCE JEDEC REGISTRATION
   TO-236, VARIATION AB, ISSUE H.
B) ALL DIMENSIONS ARE IN MILLIMETERS.
C) DIMENSIONS ARE INCLUSIVE OF BURRS,
   MOLD FLASH AND TIE BAR EXTRUSIONS.
D) DIMENSIONING AND TOLERANCING PER
   ASME Y14.5M - 2009.
E) DRAWING FILE NAME: MA03DREV12

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MegaBuck™
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™
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SMART START™
Solutions for Your Success™
SPM®
STEALTH™
SuperFET®
SuperSOT™-3
SuperSOT™-6
SuperSOT™-8
SupreMOS®
SyncFET™
Sync-Lock™

SYSTEM GENERAL®*
TinyBoost®
TinyBuck®
TinyCalc™
TinyLogic®
TINYOPTO™
TinyPower™
TinyPWM™
TinyWire™
TranSiC™
TriFault Detect™
TRUECURRENT®*
μSerDes™

SerDes™
UHC®
Ultra FRFET™
UniFET™
VCX™
VisualMax™
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XS™
Xsens™
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PRODUCT STATUS DEFINITIONS

Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative / In Design	Datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	Datasheet contains preliminary data; supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	Datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve the design.
Obsolete	Not In Production	Datasheet contains specifications on a product that is discontinued by Fairchild Semiconductor. The datasheet is for reference information only.

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